

FMV10N80E

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

Features

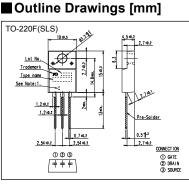
Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (4.0±0.5V) High avalanche durability

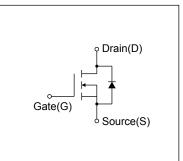
Applications

Switching regulators UPS (Uninterruptible Power Supply) **DC-DC converters**

Maximum Ratings and Characteristics

● Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)





Equivalent circuit schematic

Description	Symbol	Characteristics	Unit	Remarks
Drain Source Veltere	VDS	800	V	
Drain-Source Voltage	VDSX	800	V	V _{GS} = -30V
Continuous Drain Current	lo	±10	А	
Pulsed Drain Current	DP	±40	Α	
Gate-Source Voltage	Vgs	±30	V	
Repetitive and Non-Repetitive Maximum AvalancheCurrent	lar	10	Α	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	572.4	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	8.5	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	2.1	kV/µs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maximum Bawar Disaination	PD	2.16	10/	Ta=25°C
Maximum Power Dissipation		85	W	Tc=25°C
Oneventing and Staroge Temperature years	Tch	150	°C	
Operating and Storage Temperature range	Tstg	-55 to + 150	°C	

Electrical Characteristics at Tc=25°C (unless otherwise specified) **Static Ratings**

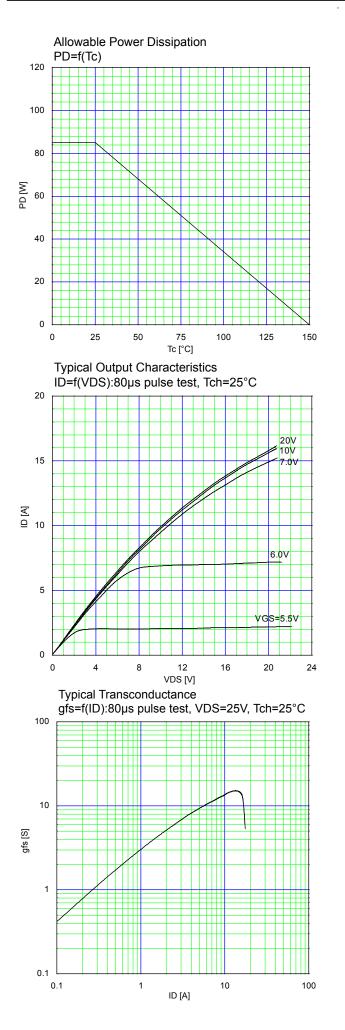
Description	Symbol	Conditions		min.	typ.	max.	Unit	
Drain-Source Breakdown Voltage	BVDSS	ID=250µA, VGS=0V		800	-	-	V	
Gate Threshold Voltage	V _{GS} (th)	ID=250µA, VDS=VGS		3.5	4.0	4.5	V	
Zero Gate Voltage Drain Current		V _{DS} =800V, V _{GS} =0V	Tch=25°C	-	-	25		
	IDSS	V _{DS} =640V, V _{GS} =0V	Tch=125°C	-	-	250	μA	
Gate-Source Leakage Current	Igss	Vgs=±30V, Vds=0V	V _{GS} =±30V, V _{DS} =0V		10	100	nA	
Drain-Source On-State Resistance	RDS (on)	ID=5.0A, VGS=10V	ID=5.0A, VGS=10V		0.9	1.1	Ω	
Forward Transconductance	g fs	ID=5.0A, VDS=25V		5.0	10	-	S	
Input Capacitance	Ciss	V _{bs} =25V V _{ss} =0V f=1MHz		-	1650	2500	pF	
Output Capacitance	Coss			-	165	250		
Reverse Transfer Capacitance	Crss			-	11	17		
Turn-On Time	td(on)			-	34	51	ns	
	tr			-	32	48		
Turn-Off Time	td(off)			-	105	160		
	tf			-	30	45		
Total Gate Charge	QG	Vcc=450V I₀=10A Vcs=10V See Fig.5		-	50	75	nC	
Gate-Source Charge	QGS			-	14	21		
Drain-Source Crossover Charge	Qsw			-	6	9		
Gate-Drain Charge	QGD			-	17	26		
Avalanche Capability	Iav	L=4.20mH, T _{ch} =25°C		10	-	-	А	
Diode Forward On-Voltage	Vsd	IF=10A, VGS=0V, Tch=25°C		-	0.90	1.35	V	
Reverse Recovery Time	trr	IF=10A, VGS=0V		-	1.8	-	μS	
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25°C		-	15	-	μC	

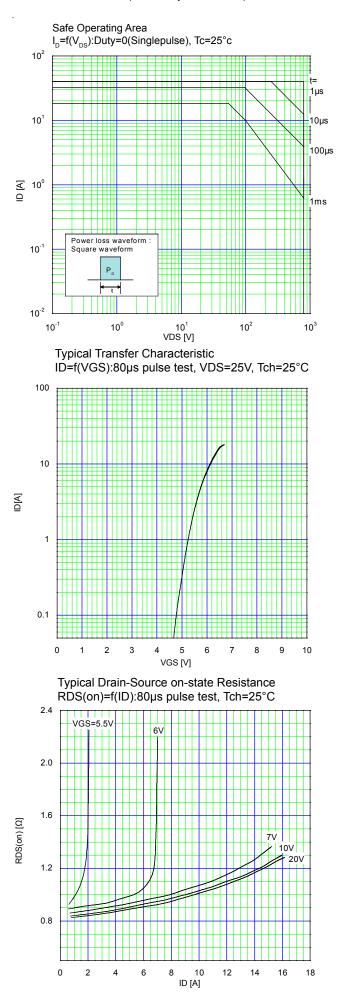
Thermal Characteristics

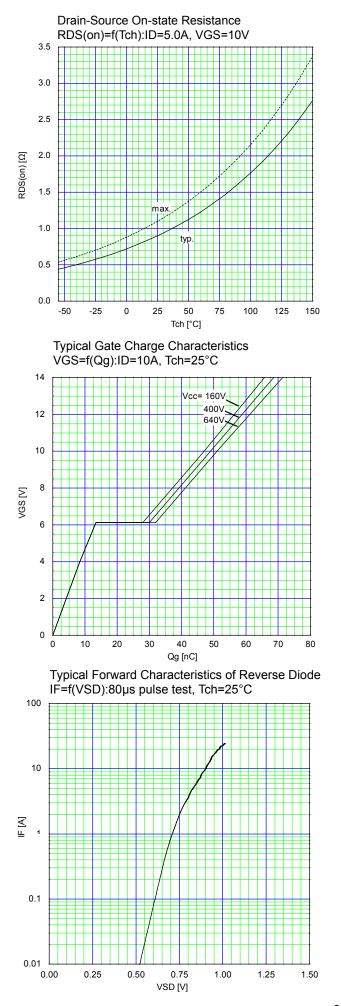
Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to case			1.471	°C/W
	Rth (ch-a)	Channel to ambient			58.0	°C/W

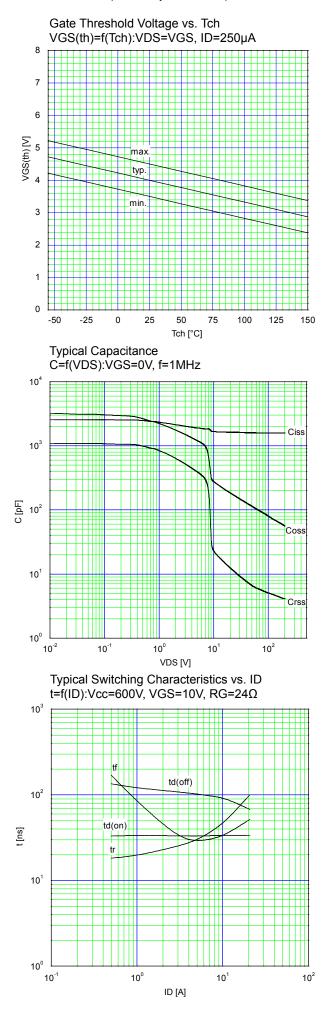
Note *1 : Tch≤150°C.

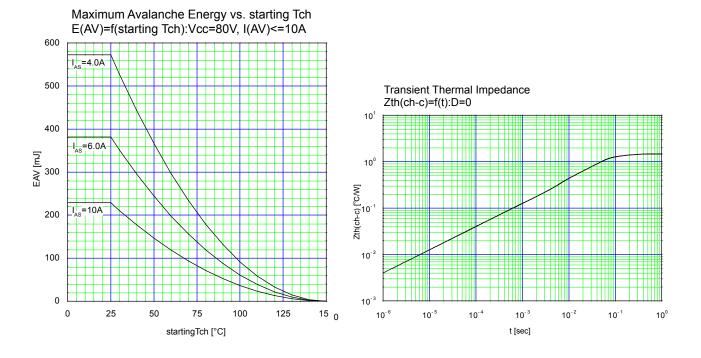
Note *2 : Stating Tch=25°C, IAs=4.0A, L=65.6mH, Vcc=80V, Rg=10Ω, Eas limited by maximum channel temperature and avalanche current. Note *3 : Repetitive rating : Pulse width limited by maximum channel temperature. Note *4 : $i_{F\leq-l_D}$, $-di/dt=100A/\mu_S$, Vcc≤BVoss, Tch≤150°C. Note *5 : $i_{F\leq-l_D}$, $dv/dt=2.1kV/\mu_S$, Vcc≤BVoss, Tch≤150°C.











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